

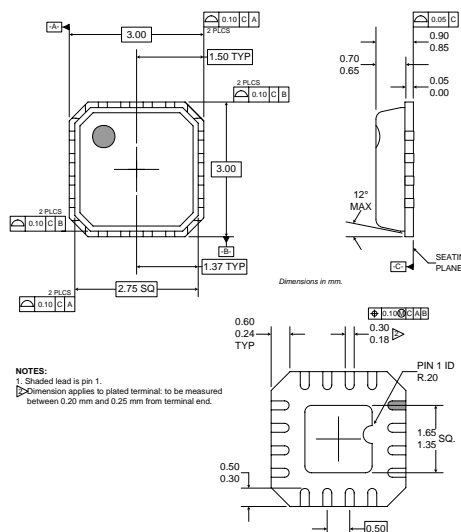
RoHS Compliant & Pb-Free Product

Typical Applications

- CDMA/JCDMA Cellular Systems
- CDMA450 Handsets/Data Cards
- AMPS Cellular Systems
- General Purpose LNA and Downconverter
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment

Product Description

The RF2861 is a receiver front-end for CDMA cellular applications, including JCDMA and CDMA450. It is designed to amplify and downconvert RF signals, using a three gain state LNA to obtain 17dB of stepped gain control. Features include digital control of LNA gain and power down mode, along with an integrated TX LO buffer amplifier. Another feature of the chip is adjustable IIP3 of the LNA and mixer using off-chip current setting resistors to allow for minimum DC current consumption. Noise figure, IIP3, and other specs are designed to be compatible with the TIA/EIA 98D standard for CDMA cellular communications. The IC is manufactured on an advanced Silicon Germanium Bi-CMOS process and is in a 3mmx3mm, 16-pin, QFN.



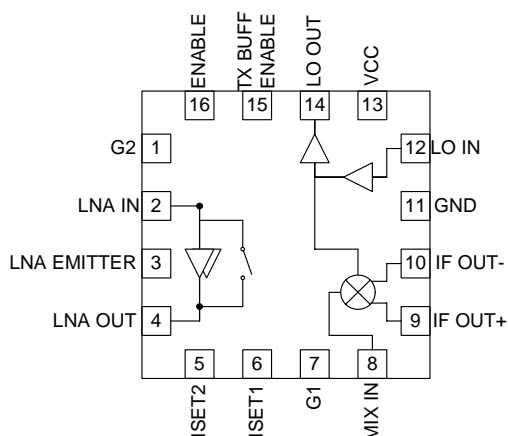
Optimum Technology Matching® Applied

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| <input type="checkbox"/> Si BJT | <input type="checkbox"/> GaAs HBT | <input type="checkbox"/> GaAs MESFET |
| <input type="checkbox"/> Si Bi-CMOS | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si CMOS |
| <input type="checkbox"/> InGaP/HBT | <input type="checkbox"/> GaN HEMT | <input checked="" type="checkbox"/> SiGe Bi-CMOS |

Package Style: QFN, 16-Pin, 3x3

Features

- 3mmx3mm LNA/Mixer Solution
- Adjustable LNA and Mixer Current/IIP3
- Meets IMD Tests with Three Gain States/Two Logic Control Pins
- Integrated TX LO Buffer Amplifier
- Full ESD Protection on all Pins



Functional Block Diagram

Ordering Information

- | | |
|----------------|---|
| RF2861 | CDMA Low Noise Amplifier/Mixer 900MHz Downconverter |
| RF2861PCBA-41X | Fully Assembled Evaluation Board |

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RF2861

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +5.0	V _{DC}
Input LO and RF Levels	+6	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



Caution! ESD sensitive device.

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Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					T = 25°C, V _{CC} =2.75V
RF Frequency Range		460 to 900		MHz	
IF Frequency Range	0.1		400	MHz	
Power Supply					
Supply Voltage	2.65	2.75	3.15	V	
Logic High	1.8			V	
Logic Low			0.4	V	
Cellular CDMA Band					Freq=869MHz to 894MHz
JCDMA Band					Freq=832MHz to 870MHz
LNA (High Gain)					LNA 50Ω match
Gain	13.0	14.5	16.0	dB	
Noise Figure		1.1	1.3	dB	
Input IP3	9.0	11.0		dBm	
Current		7.0		mA	
Isolation	18.5			dB	
LNA (Mid Gain)					
Gain	4.0	6.0	7.0	dB	
Noise Figure		3.0	3.3	dB	
Input IP3	7.0	9.0		dBm	
Current		3.5		mA	
Isolation	12.5			dB	
LNA (Low Gain)					
Gain	-4.0	-2.5	-1.0	dB	
Noise Figure		2.5	4.0	dB	
Input IP3	+25.0	+27.0		dBm	
Current		0		mA	
Isolation	1.0			dB	
Mixer - CDMA/JCDMA/FM					IF tune set for nominal mixer gain, high IIP3
Gain	9.0	10.5	12.0	dB	
Noise Figure		7.5	8.0	dB	184MHz IF (NF=8.3dB, 85MHz IF)
Input IP3	+6.0	+8.5		dBm	
LO to RF Isolation	36			dB	LO=1064MHz
Mixer - CDMA/JCDMA/FM					IF tune set for high mixer gain, nominal IIP3
Gain		13.0		dB	
Noise Figure		7.5		dB	184MHz IF (NF=8.3dB, 85MHz IF)
Input IP3		+6.5		dBm	
LO to RF Isolation	36			dB	LO=1064MHz
Cascade - High Gain					
Current		25	30	mA	TX LO Buffer Off

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Cellular CDMA Band					
JCDMA Band, cont'd					
Other					
LO-IF Isolation	30			dB	LO=1064MHz
RF-IF Isolation	45			dB	
LNA Out to Mixer In Isolation	45			dB	
LO-LNA In Isolation, Any State	40			dB	LO=1064MHz
Control Lines					
Input Capacitance			1	pF	G1, G2, ENABLE, TX BUFF ENABLE
Local Oscillator Input					
Cellular - CDMA or FM					
Input Power	-10	-4	0	dBm	
Input Frequency	685		710	MHz	IF=184MHz
	1053		1078	MHz	IF=184MHz
	784		809	MHz	IF=85MHz
	954		979	MHz	IF=85MHz
Cellular - JCDMA					
Input Power	-10	-4	0	dBm	
Input Frequency	722		760	MHz	IF=110MHz
	942		980	MHz	IF=110MHz
CDMA450					
Input Power	-10	-4	0	dBm	
Input Frequency	505		575	MHz	IF=85MHz
CDMA450 Band					Freq=463MHz to 467MHz
LNA (High Gain)					LNA 50Ω match
Gain		15.0		dB	
Noise Figure		1.4		dB	
Input IP3		+8.0		dBm	
Current		8.7		mA	
Isolation	18.5			dB	
LNA (Mid Gain)					
Gain		+2.5		dB	
Noise Figure		2.9		dB	
Input IP3		+14.0		dBm	
Current		4.7		mA	
Isolation	12.5			dB	
LNA (Low Gain)					
Gain		-4.0		dB	
Noise Figure		4.0		dB	
Input IP3		+25.0		dBm	
Current		0		mA	
Isolation	1.0			dB	
Mixer					IF tune set for high mixer gain, nominal IIP3
Gain		12.0		dB	
Noise Figure		7.5		dB	
Input IP3		5.0		dBm	
LO to RF Isolation	36			dB	LO=549MHz
CDMA450 Isolation					
LO-IF Isolation	25			dB	LO=549MHz
RF-IF Isolation	40			dB	
LNA Out to Mixer In Isolation	40			dB	
LO-LNA In Isolation, Any State	30			dB	LO=549MHz

Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
TX (Local Oscillator)					
Buffer Output					
Cellular - CDMA or FM					
Output Power	-7	-5	-3	dBm	Single-ended 50Ω load
Output Frequency	685		710	MHz	IF=184MHz
	1053		1078	MHz	IF=184MHz
	784		809	MHz	IF=85MHz
	954		979	MHz	IF=85MHz
Current Consumption		2		mA	
Cellular - JCDMA					
Output Power	-7	-5	-3	dBm	Single-ended 50Ω load
Output Frequency	722		760	MHz	IF=110MHz
	942		980	MHz	IF=110MHz
Current Consumption		2		mA	
CDMA450					
Output Power	-7	-5	-3	dBm	Single-ended 50Ω load
Output Frequency	505		575	MHz	IF=85MHz
Current Consumption		2		mA	

Gain Control Logic Table

Gain State	ENABLE	G1	G2
High Gain	1	0	0
Mid Gain	1	1	0
Low Gain	1	1	1
Low Gain (alternate)	1	0	1

NOTES: All IDC current numbers include bias circuitry current of 1.5mA to 2.0mA (dependent on mode).
TX Buffer On: Add 2mA to total current.

Cell Band Cascaded Performance High Mixer Gain Nominal IIP3 (Typical Values for $V_{CC}=2.75V$)

NOTE: All total current numbers include bias circuitry current of 1.5mA to 2.0mA (dependent on mode).

Parameter	CELL CDMA		
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)
Cascaded:			
Gain (dB)	25.0	16.5	8.0
Noise Figure (dB)	2.1	6.3	12.5
Input IP3 (dBm)	-5.6	+2.0	+11.4
Total Current (mA)	25.0	21.5	18.0

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

Cell Band Cascaded Performance Nominal Mixer Gain High IIP3 (Typical Values for $V_{CC}=2.75V$)

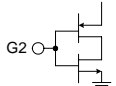
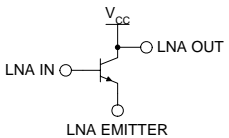
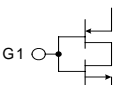
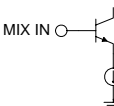
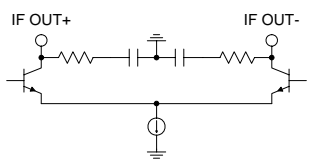
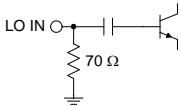

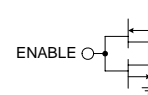
Parameter	CELL CDMA		
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)
Cascaded:			
Gain (dB)	22.5	14.0	5.5
Noise Figure (dB)	2.1	6.3	12.5
Input IP3 (dBm)	-3.7	+3.5	+13.3
Total Current (mA)	25.0	21.5	18.0

NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

CDMA450 Band Cascaded Performance (Typical Values for $V_{CC}=2.75V$)

Parameter	CDMA450		
	LNA (High Gain)	LNA (Mid Gain)	LNA (Low Gain)
Cascaded:			
Gain (dB)	24.5	12.0	5.5
Noise Figure (dB)	2.2	8.5	14.0
Input IP3 (dBm)	-7.6	+4.5	+11.3
Total Current (mA)	29.5	25	21

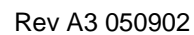
NOTE: Assumes 2.5dB image filter insertion loss. The TX Buffer is off.

Pin	Function	Type	Description	Interface Schematic
1	G2	DI	Gain control logic input. See logic control table.	
2	LNA IN	AI	Cellular LNA input.	
3	LNA EMITTER	AO	Cellular LNA emitter. A small inductor connects this pin to ground. Cellular LNA gain can be adjusted by the inductance.	See pin 2.
4	LNA OUT	AO	Cellular LNA output. Simple external L-C components required for matching and VCC supply.	See pin 2.
5	ISSET2	AO	An external resistor connected to this pin sets the current of the mixer. Increasing resistance decreases current.	
6	ISSET1	AO	An external resistor connected to this pin sets the current of the LNA. Increasing resistance decreases current.	
7	G1	DI	Gain control logic input. See logic control table.	
8	MIX IN	AI	Cellular mixer RF single-end input.	
9	IF OUT+	AO	CDMA IF output. Open collector.	
10	IF OUT-	AO	CDMA IF output. Open collector.	See pin 9.
11	GND	P	Ground.	
12	LO IN	AI	LO single-end input. Matched to 50Ω.	
13	VCC	P	LO amplifier VCC external bypass capacitor may be required.	
14	LO OUT	AO	LO output. Internal DC block. Drives 50Ω.	
15	TX BUFF ENABLE	DI	Logic input. High enables TX LO output buffer amplifiers.	
16	ENABLE	DI	Logic input. Low level powers down the IC.	
Pkg Base	GND	P	Ground connection. The backside of the package should be soldered to a top side ground pad which is connected to the ground plane with multiple vias.	

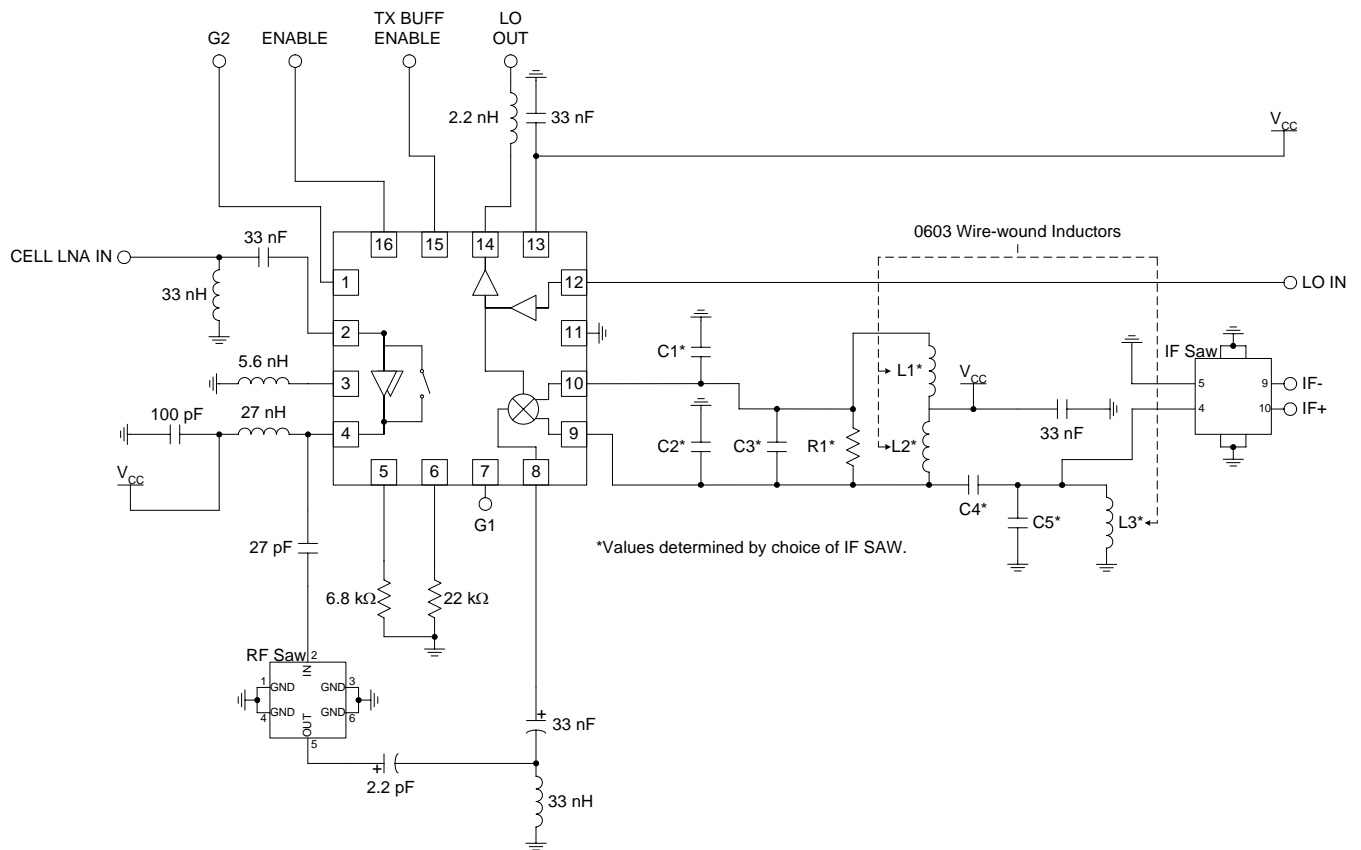
Legend:

DI=Digital Input from Baseband Chip
P= V_{CC} or GND

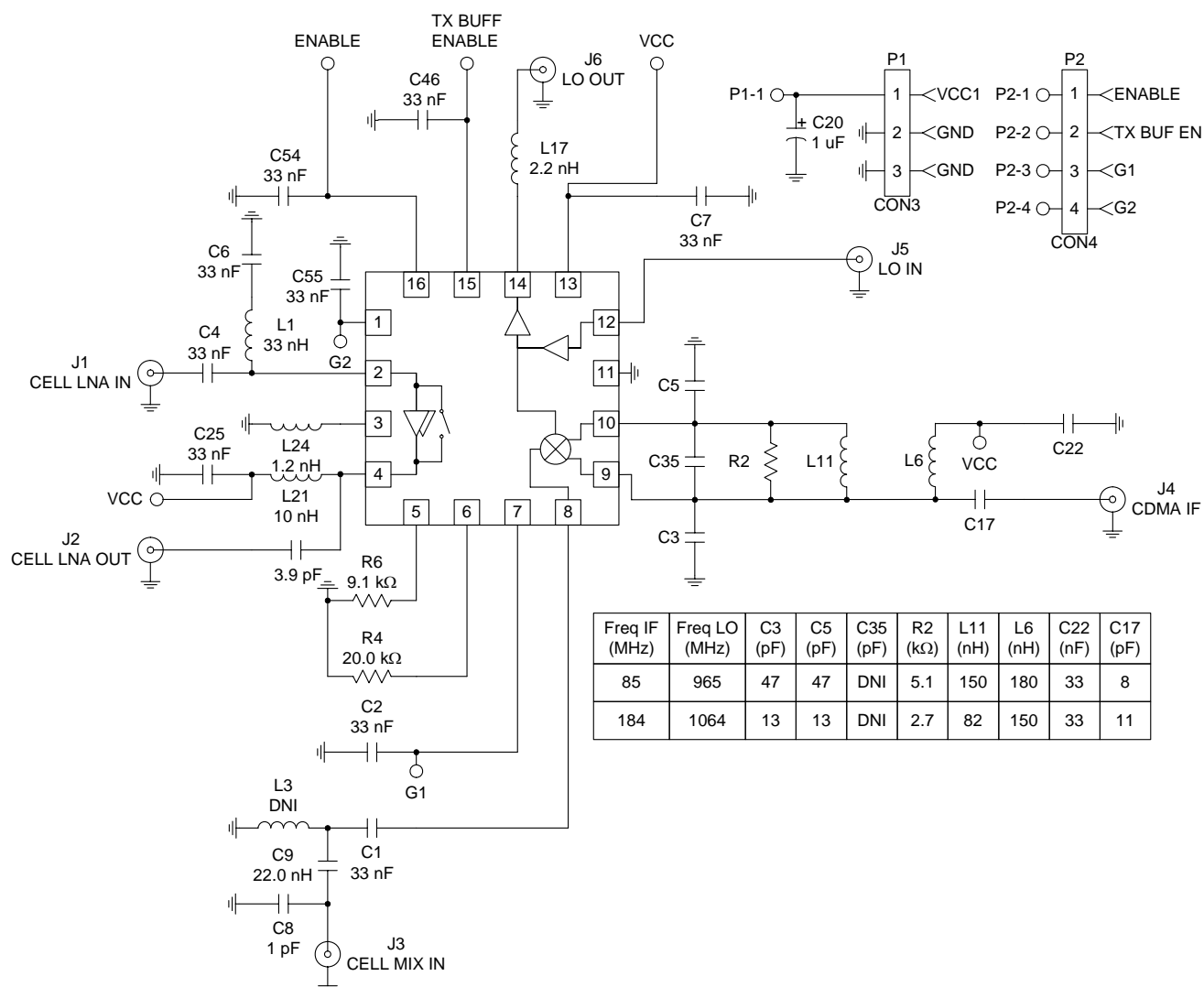
AI=Analog Input
AO=Analog Output



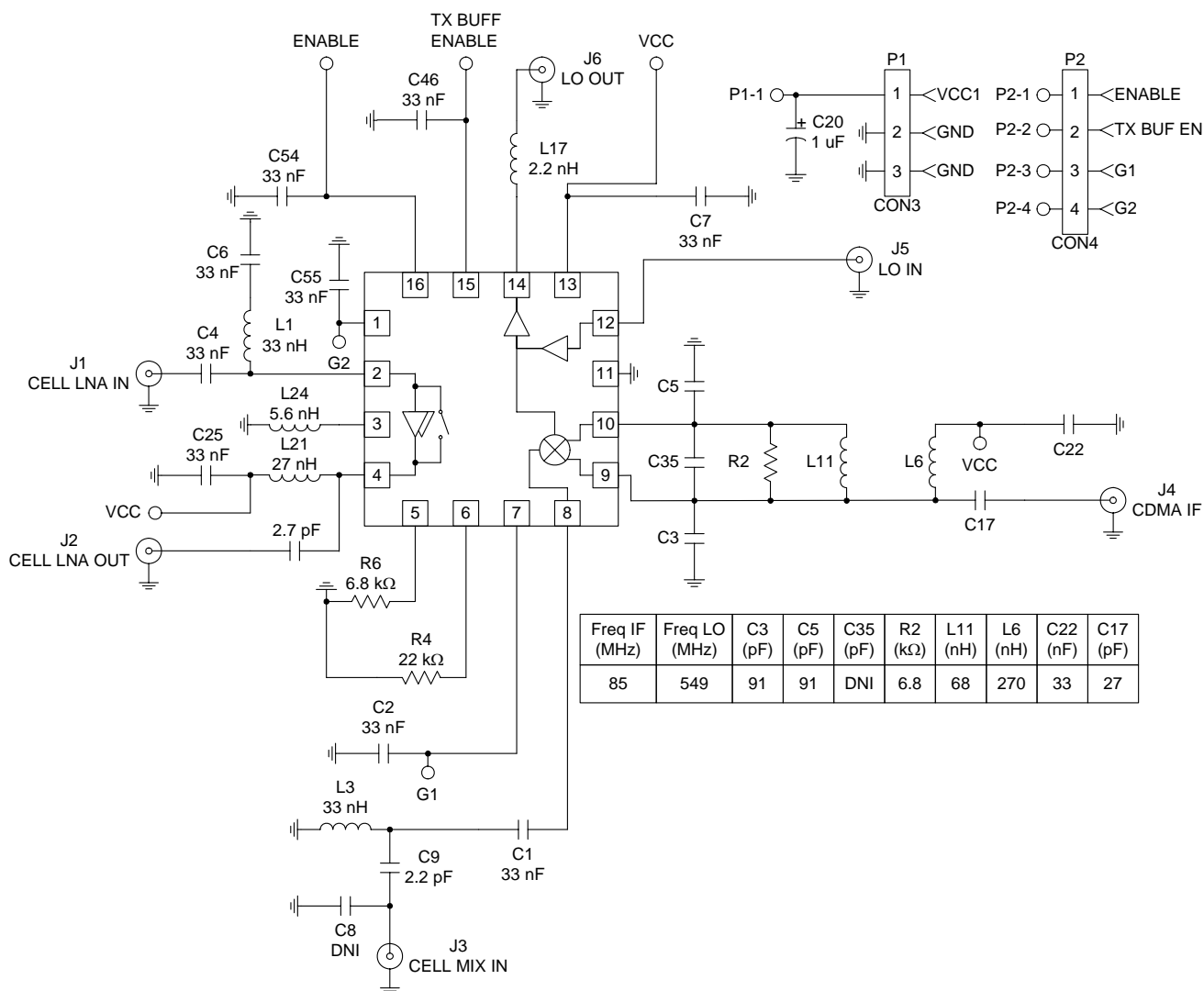
Application Schematic Single-End Matching CDMA450 Band



Evaluation Board Schematic

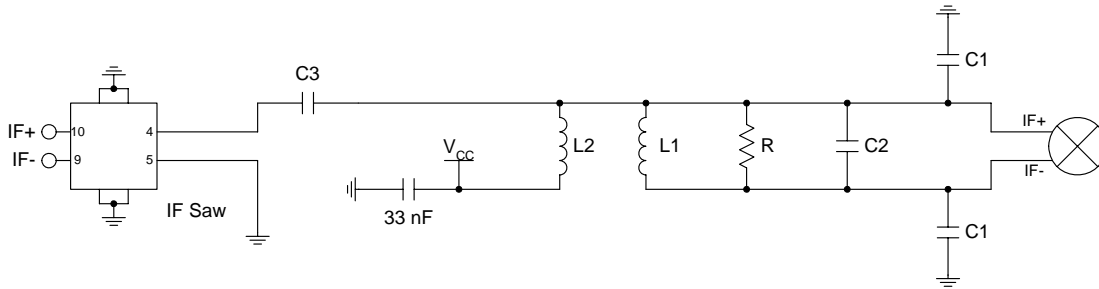


Evaluation Board Schematic CDMA450 Band



IF Output Interface Network

Single-End IF Matching



L1, C1, C2, and R form a current combiner which performs a differential to single-ended conversion at the IF frequency and sets the output impedance. In most cases, the resonance frequency is independent of R and can be set according to the following equation:

$$f_{IF} = \frac{1}{2\pi\sqrt{\frac{L1}{2}(C_1 + 2C_2 + C_{EQ})}}$$

Where C_{EQ} is the equivalent stray capacitance and capacitance looking into pins 9 and 10. An average value to use for C_{EQ} is 2.5pF.

R can then be used to set the output impedance according to the following equation:

$$R = \left(\frac{1}{4 \cdot R_{OUT}} - \frac{1}{R_P} \right)^{-1}$$

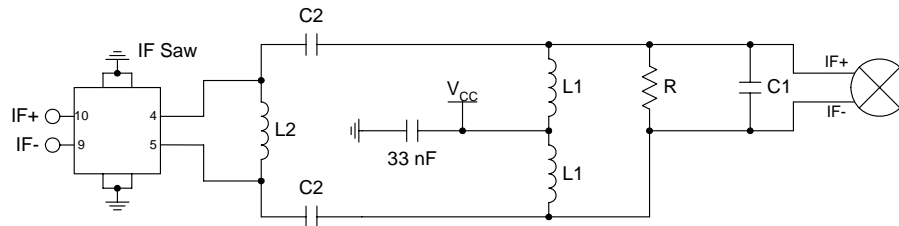
where R_{OUT} is the desired output impedance and R_P is the parasitic equivalent parallel resistance of L1.

C_2 should first be set to 0 and C_1 should be chosen as high as possible (not greater than 39pF), while maintaining an R_P of L1 that allows for the desired R_{OUT} . If the self-resonant frequencies of the selected C_1 produce unsatisfactory linearity performance, their values may be reduced and compensated for by including C_2 capacitor with a value chosen to maintain the desired F_{IF} frequency.

L2 and C3 serve dual purposes. L2 serves as an output bias choke, and C3 serves as a series DC block.

In addition, L2 and C3 may be chosen to form an impedance matching network if the input impedance of the IF filter is not equal to R_{OUT} . Otherwise, L2 is chosen to be large (suggested 120nH) and C3 is chosen to be large (suggested 22nF) if a DC path to ground is present in the IF filter, or omitted if the filter is DC-blocked.

Differential IF Matching



L1 and C1 are chosen to resonate at the desired IF frequency. C1 can be omitted and the value of L1 increased and utilized solely as a choke to provide V_{CC} to the open-collector outputs, but it is strongly recommended that at least some small-valued C1 (a few pF) be retained for better mixer linearity performance. R is normally selected to match the input impedance of the IF filter. However, mixer performance can be modified by selecting an R value that is different from the IF filter input impedance, and inserting a conjugate matching network between the Resistive Output Network and the IF filter.

C2 serve dual purposes. C2 serves as a series DC block when a DC path to ground is present in the IF filter. In addition, C2 may be chosen to improve the combine performance of the mixer and IF filter. L2 should choose to resonate with the internal capacitance of the SAW filter. Usually, SAW filter has some capacitance. Otherwise, L2 could be eliminated.

A practical approach to obtain the differential matching is to tune the mixer to the correct load point for gain, IIP3, and NF using the single-end current combiner method. Second, use the component values found in the single-end approach as starting point for the differential matching. The two-shunt capacitors in the single-end could be converted in a parallel capacitor and the parallel inductor in the single-end need to be converted in two-choke inductor. Third, set the DC block capacitors (C2) in the differential-end matching to a high value (i.e., 100pF) and retune the resonate circuit (C1 & L1) and the resistor (R) for optimal performance. After optimal performance is achieved and if performance is not satisfactory, decrease the series capacitors until optimal performance is achieved.

